

LOW-VOLTAGE RAIL-TO-RAIL OUTPUT OPERATIONAL AMPLIFIERS

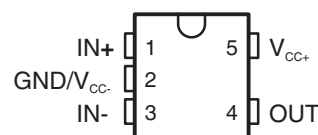
Check for Samples: [LMV821-Q1](#), [LMV822-Q1](#), [LMV824-Q1](#)

FEATURES

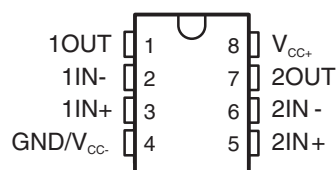
- **Qualified for Automotive Applications**
- **2.5-V, 2.7-V, and 5-V Performance**
- **–40°C to 125°C Operation**
- **No Crossover Distortion**
- **Low Supply Current at $V_{CC+} = 5\text{ V}$**
 - LMV821: 0.3 mA Typ
 - LMV822: 0.5 mA Typ
 - LMV824: 1 mA Typ
- **Rail-to-Rail Output Swing**
- **Gain Bandwidth of 5.5 MHz Typ at 5 V**
- **Slew Rate of 1.9 V/ μs Typ at 5 V**

The LMV82x devices are characterized for operation from –40°C to 125°C.

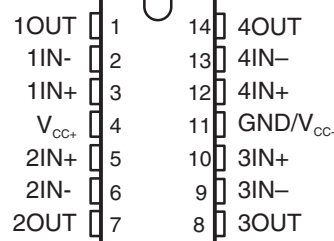
**LMV821...DBV PACKAGE
(TOP VIEW)**



**LMV822...DGK PACKAGE
(TOP VIEW)**



**LMV824...D OR PW PACKAGE
(TOP VIEW)**



DESCRIPTION/ORDERING INFORMATION

The LMV821 single, LMV822 dual, and LMV824 quad devices are low-voltage (2.5 V to 5.5 V), low-power commodity operational amplifiers. Electrical characteristics are very similar to the LMV3xx operational amplifiers (low supply current, rail-to-rail outputs, input common-mode range that includes ground). However, the LMV82x devices offer a higher bandwidth (5.5 MHz typical) and faster slew rate (1.9 V/ μs typical).

The LMV82x devices are cost-effective solutions for applications requiring low-voltage/low-power operation and space-saving considerations. The LMV821 saves space on printed circuit boards and enables the design of small portable electronic devices (cordless and cellular phones, laptops, PDAs, PCMIA). It also allows the designer to place the device closer to the signal source to reduce noise pickup and increase signal integrity.

ORDERING INFORMATION⁽¹⁾

T_A	PACKAGE ⁽²⁾			ORDERABLE PART NUMBER	TOP-SIDE MARKING ⁽³⁾
–40°C to 125°C	Single	SOT-23 – DBV	Reel of 3000	LMV821QDBVRQ1	RB1_
	Dual	MSOP/VSSOP – DGK	Reel of 2500	LMV822QDGKRQ1	R8B
	Quad	SOIC – D	Reel of 2500	LMV824QDRQ1	LMV824Q
		TSSOP – PW	Reel of 2000	LMV824QPWRQ1	MV824Q

(1) For the most current package and ordering information, see the Package Option Addendum at the end of this document, or see the TI web site at www.ti.com.

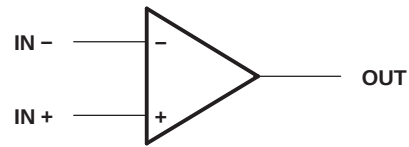
(2) Package drawings, thermal data, and symbolization are available at www.ti.com/packaging.

(3) DBV: The actual top-side marking has one additional character that designates the wafer fab/assembly site.

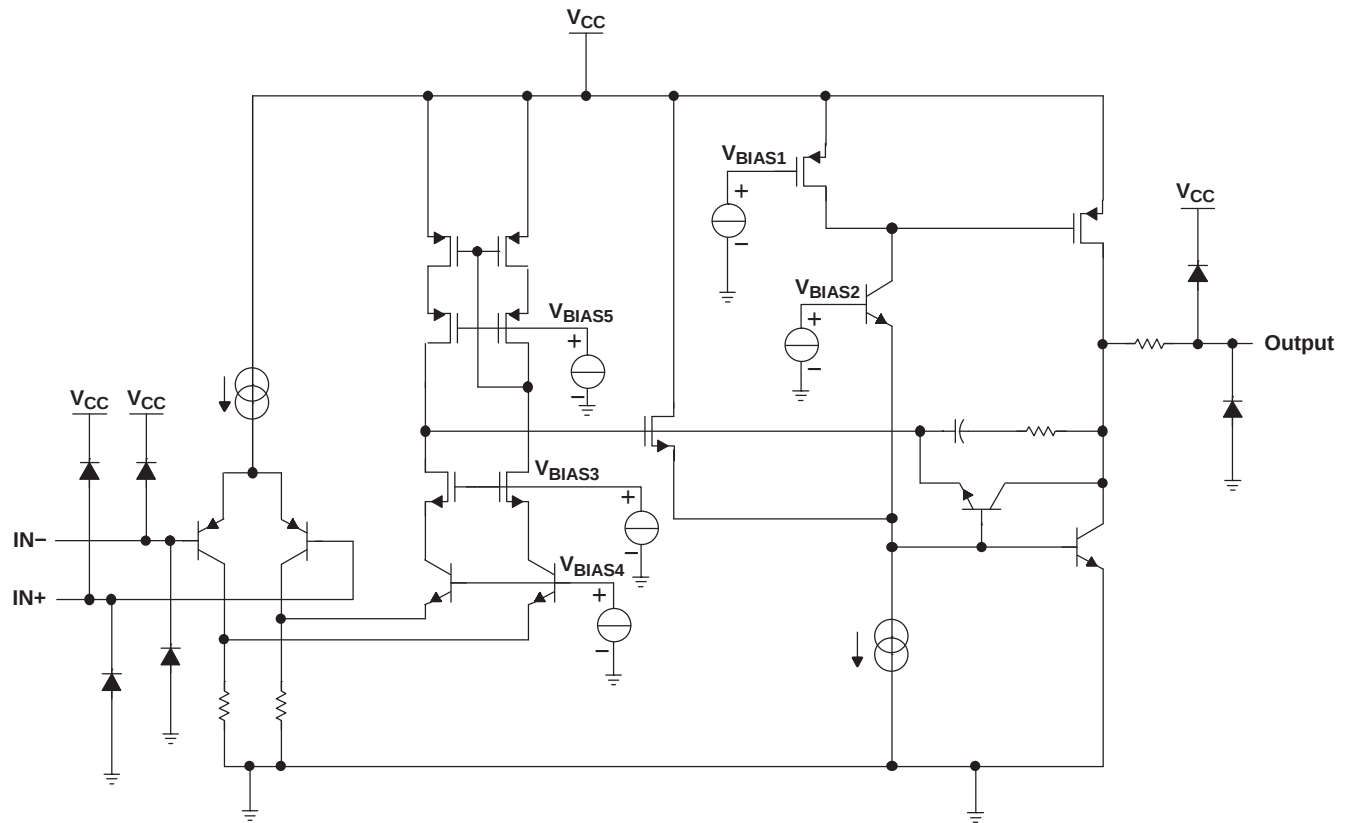


Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

SYMBOL (EACH AMPLIFIER)



SIMPLIFIED SCHEMATIC



ABSOLUTE MAXIMUM RATINGS⁽¹⁾

over operating free-air temperature range (unless otherwise noted)

V_{CC}	Supply voltage ⁽²⁾	5.5 V
V_{ID}	Differential input voltage ⁽³⁾	$\pm V_{CC}$
V_I	Input voltage range (either input)	V_{CC-} to V_{CC+}
	Duration of output short circuit (one amplifier) to ground ⁽⁴⁾	At or below $T_A = 25^\circ\text{C}$, $V_{CC} \leq 5.5\text{ V}$
θ_{JA}	Package thermal impedance ⁽⁵⁾ ⁽⁶⁾	Unlimited
		D package
		97°C/W
		DBV package
		206°C/W
		DGK package
		172°C/W
		PW package
		113°C/W
T_J	Operating virtual-junction temperature	150°C
T_{stg}	Storage temperature range	–65°C to 150°C

- (1) Stresses beyond those listed under *absolute maximum ratings* may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under *recommended operating conditions* is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
- (2) All voltage values (except differential voltages and V_{CC} specified for the measurement of I_{OS}) are with respect to the network GND.
- (3) Differential voltages are at IN+ with respect to IN–.
- (4) Short circuits from outputs to V_{CC} can cause excessive heating and eventual destruction.
- (5) Maximum power dissipation is a function of $T_J(\text{max})$, θ_{JA} , and T_A . The maximum allowable power dissipation at any allowable ambient temperature is $P_D = (T_J(\text{max}) - T_A)/\theta_{JA}$. Operating at the absolute maximum T_J of 150°C can affect reliability.
- (6) The package thermal impedance is calculated in accordance with JESD 51-7.

RECOMMENDED OPERATING CONDITIONS

	MIN	MAX	UNIT
V_{CC} Supply voltage (single-supply operation)	2.5	5	V
T_A Operating free-air temperature	–40	125	°C

2.5-V ELECTRICAL CHARACTERISTICS

 $V_{CC+} = 2.5\text{ V}$, $V_{CC-} = 0\text{ V}$, $V_{IC} = 1\text{ V}$, $V_O = 1.25\text{ V}$, and $R_L > 1\text{ M}\Omega$ (unless otherwise noted)

PARAMETER	TEST CONDITIONS	T_A	MIN	TYP	MAX	UNIT
V_{IO} Input offset voltage		25°C		1	6	mV
		–40°C to 125°C			6	
V_O Output swing	$V_{CC+} = 2.5\text{ V}$, $R_L = 600\ \Omega$ to 1.25 V	High level	25°C	2.28	2.37	V
			–40°C to 125°C	2.18		
		Low level	25°C	0.13	0.22	
			–40°C to 125°C		0.32	
	$V_{CC+} = 2.5\text{ V}$, $R_L = 2\text{ k}\Omega$ to 1.25 V	High level	25°C	2.38	2.46	
			–40°C to 125°C	2.28		
		Low level	25°C	0.08	0.14	
			–40°C to 125°C		0.22	

2.7-V ELECTRICAL CHARACTERISTICS

$V_{CC+} = 2.7\text{ V}$, $V_{CC-} = 0\text{ V}$, $V_{IC} = 1\text{ V}$, $V_O = 1.35\text{ V}$, and $R_L > 1\text{ M}\Omega$ (unless otherwise noted)

PARAMETER		TEST CONDITIONS		T_A	MIN	TYP	MAX	UNIT
V_{IO}	Input offset voltage			25°C		1	6	mV
				–40°C to 125°C			6	
α_{VIO}	Average temperature coefficient of input offset voltage			25°C		1		$\mu\text{V}/^\circ\text{C}$
I_{IB}	Input bias current			25°C		30	90	nA
				–40°C to 125°C			140	
I_{IO}	Input offset current			25°C		0.5	30	nA
				–40°C to 125°C			50	
CMRR	Common-mode rejection ratio	$V_{IC} = 0\text{ to }1.7\text{ V}$		25°C	70	85		dB
				–40°C to 125°C	68			
+ k_{SVR}	Positive supply-voltage rejection ratio	$V_{CC+} = 1.7\text{ V to }4\text{ V}$, $V_{CC-} = -1\text{ V}$, $V_O = 0$, $V_{IC} = 0$		25°C	75	85		dB
				–40°C to 125°C	70			
– k_{SVR}	Negative supply-voltage rejection ratio	$V_{CC+} = 1.7\text{ V}$, $V_{CC-} = -1\text{ V to }-3.3\text{ V}$, $V_O = 0$, $V_{IC} = 0$		25°C	73	85		dB
				–40°C to 125°C	70			
V_{ICR}	Common-mode input voltage range	CMRR $\geq 50\text{ dB}$		25°C	–0.2 to 1.9	–0.3 to 2		V
A_V	Large-signal voltage amplification	$R_L = 600\text{ }\Omega\text{ to }1.35\text{ V}$, $V_O = 1.35\text{ V to }2.2\text{ V}$	Sourcing	25°C	90	100		dB
				–40°C to 125°C	85			
		$R_L = 600\text{ }\Omega\text{ to }1.35\text{ V}$, $V_O = 1.35\text{ V to }0.5\text{ V}$	Sinking	25°C	85	90		
				–40°C to 125°C	80			
		$R_L = 2\text{ k}\Omega\text{ to }1.35\text{ V}$, $V_O = 1.35\text{ V to }2.2\text{ V}$	Sourcing	25°C	95	100		
				–40°C to 125°C	90			
		$R_L = 2\text{ k}\Omega\text{ to }1.35\text{ V}$, $V_O = 1.35\text{ V to }0.5\text{ V}$	Sinking	25°C	90	95		
				–40°C to 125°C	85			
V_O	Output swing	$V_{CC+} = 2.7\text{ V}$, $R_L = 600\text{ }\Omega\text{ to }1.35\text{ V}$	High level	25°C	2.5	2.58		V
				–40°C to 125°C	2.4			
			Low level	25°C		0.13	0.2	
				–40°C to 125°C			0.3	
		$V_{CC+} = 2.7\text{ V}$, $R_L = 2\text{ k}\Omega\text{ to }1.35\text{ V}$	High level	25°C	2.6	2.66		
				–40°C to 125°C	2.5			
			Low level	25°C		0.08	0.12	
				–40°C to 125°C			0.2	
I_O	Output current	$V_O = 0\text{ V}$	Sourcing	25°C	12	16		mA
		$V_O = 2.7\text{ V}$	Sinking	25°C	12	26		
I_{CC}	Supply current	LMV821		25°C		0.22	0.3	mA
				–40°C to 125°C			0.5	
		LMV822 (both amplifiers)		25°C		0.45	0.6	
				–40°C to 125°C			0.8	
		LMV824 (all four amplifiers)		25°C		0.72	1	
				–40°C to 125°C			1.2	

2.7-V ELECTRICAL CHARACTERISTICS (continued)

$V_{CC+} = 2.7\text{ V}$, $V_{CC-} = 0\text{ V}$, $V_{IC} = 1\text{ V}$, $V_O = 1.35\text{ V}$, and $R_L > 1\text{ M}\Omega$ (unless otherwise noted)

PARAMETER		TEST CONDITIONS	T_A	MIN	TYP	MAX	UNIT
SR	Slew rate ⁽¹⁾		25°C		1.7		V/ μ s
GBW	Gain bandwidth product	⁽²⁾	25°C		5		MHz
Φ_m	Phase margin	⁽²⁾	25°C		60		deg
	Gain margin	⁽²⁾	25°C		8.6		dB
	Amplifier-to-amplifier isolation	$V_{CC+} = 5\text{ V}$, $R_L = 100\text{ k}\Omega$ to 2.5 V ⁽³⁾	25°C		135		dB
V_n	Equivalent input noise voltage	$f = 1\text{ kHz}$, $V_{IC} = 1\text{ V}$	25°C		45		nV/ $\sqrt{\text{Hz}}$
I_n	Equivalent input noise current	$f = 1\text{ kHz}$	25°C		0.18		pA/ $\sqrt{\text{Hz}}$
THD	Total harmonic distortion	$f = 1\text{ kHz}$, $A_V = -2$, $R_L = 10\text{ k}\Omega$, $V_O = 4.1\text{ V}_{p-p}$	25°C		0.01		%

(1) Connected as voltage follower with 1-V step input. Value specified is the slower of the positive and negative slew rates.

(2) 40-dB closed-loop dc gain, $C_L = 22\text{ pF}$

(3) Each amplifier excited in turn with 1 kHz to produce $V_O = 3\text{ V}_{p-p}$

5-V ELECTRICAL CHARACTERISTICS

$V_{CC+} = 5\text{ V}$, $V_{CC-} = 0\text{ V}$, $V_{IC} = 2\text{ V}$, $V_O = 2.5\text{ V}$, and $R_L > 1\text{ M}\Omega$ (unless otherwise noted)

PARAMETER		TEST CONDITIONS		T _A	MIN	TYP	MAX	UNIT
V _{IO}	Input offset voltage			25°C		1	6	mV
				−40°C to 125°C			6	
α _{VIO}	Average temperature coefficient of input offset voltage			25°C		1		μV/°C
I _{IB}	Input bias current			25°C		40	100	nA
				−40°C to 125°C			150	
I _{IO}	Input offset current			25°C		0.5	30	nA
				−40°C to 125°C			50	
CMRR	Common-mode rejection ratio	V _{IC} = 0 to 4 V		25°C	72	90		dB
				−40°C to 125°C	70			
+k _{SVR}	Positive supply-voltage rejection ratio	V _{CC+} = 1.7 V to 4 V, V _{CC−} = −1 V, V _O = 0, V _{IC} = 0		25°C	75	85		dB
				−40°C to 125°C	70			
−k _{SVR}	Negative supply-voltage rejection ratio	V _{CC+} = 1.7 V, V _{CC−} = −1 V to −3.3 V, V _O = 0, V _{IC} = 0		25°C	73	85		dB
				−40°C to 125°C	70			
V _{ICR}	Common-mode input voltage range	CMRR ≥ 50 dB		25°C	−0.2 to 4.2	−0.3 to 4.3		V
A _V	Large-signal voltage amplification	R _L = 600 Ω to 2.5 V, V _O = 2.5 V to 4.5 V	Sourcing	25°C	95	105		dB
				−40°C to 125°C	90			
		R _L = 600 Ω to 2.5 V, V _O = 2.5 V to 0.5 V	Sinking	25°C	95	105		
				−40°C to 125°C	90			
		R _L = 2 kΩ to 2.5 V, V _O = 2.5 V to 4.5 V	Sourcing	25°C	95	105		
				−40°C to 125°C	90			
		R _L = 2 kΩ to 2.5 V, V _O = 2.5 V to 0.5 V	Sinking	25°C	95	105		
				−40°C to 125°C	90			
V _O	Output swing	V _{CC+} = 5 V, R _L = 600 Ω to 2.5 V	High level	25°C	4.75	4.84		V
				−40°C to 125°C	4.6			
			Low level	25°C		0.17	0.25	
				−40°C to 125°C			0.3	
		V _{CC+} = 5 V, R _L = 2 kΩ to 2.5 V	High level	25°C	4.85	4.9		
				−40°C to 125°C	4.8			
			Low level	25°C		0.1	0.15	
				−40°C to 125°C			0.2	
I _O	Output current	V _O = 0 V	Sourcing	25°C	20	45		mA
				−40°C to 125°C	15			
		V _O = 5 V	Sinking	25°C	20	40		
				−40°C to 125°C	15			
I _{CC}	Supply current	LMV821		25°C		0.3	0.4	mA
				−40°C to 125°C			0.6	
		LMV822 (both amplifiers)		25°C		0.5	0.7	
				−40°C to 125°C			0.9	
		LMV824 (all four amplifiers)		25°C		1	1.3	
				−40°C to 125°C			1.5	

5-V ELECTRICAL CHARACTERISTICS (continued)

 $V_{CC+} = 5\text{ V}$, $V_{CC-} = 0\text{ V}$, $V_{IC} = 2\text{ V}$, $V_O = 2.5\text{ V}$, and $R_L > 1\text{ M}\Omega$ (unless otherwise noted)

PARAMETER		TEST CONDITIONS	T_A	MIN	TYP	MAX	UNIT
SR	Slew rate	$V_{CC+} = 5\text{ V}^{(1)}$	25°C	1.4	1.9		V/ μ s
GBW	Gain bandwidth product	⁽²⁾	25°C		5.5		MHz
Φ_m	Phase margin	⁽²⁾	25°C		64.2		deg
	Gain margin	⁽²⁾	25°C		8.7		dB
	Amplifier-to-amplifier isolation	$V_{CC+} = 5\text{ V}$, $R_L = 100\text{ k}\Omega$ to $2.5\text{ V}^{(3)}$	25°C		135		dB
V_n	Equivalent input noise voltage	$f = 1\text{ kHz}$, $V_{IC} = 1\text{ V}$	25°C		42		nV/ $\sqrt{\text{Hz}}$
I_n	Equivalent input noise current	$f = 1\text{ kHz}$	25°C		0.2		pA/ $\sqrt{\text{Hz}}$
THD	Total harmonic distortion	$f = 1\text{ kHz}$, $A_V = -2$, $R_L = 10\text{ k}\Omega$, $V_O = 4.1\text{ V}_{p-p}$	25°C		0.01		%

(1) Connected as voltage follower with 3-V step input. Value specified is the slower of the positive and negative slew rates.

(2) 40-dB closed-loop dc gain, $C_L = 22\text{ pF}$

(3) Each amplifier excited in turn with 1 kHz to produce $V_O = 3\text{ V}_{p-p}$

TYPICAL CHARACTERISTICS

$T_A = 25^\circ\text{C}$, $V_{CC+} = 5\text{-V}$ single supply (unless otherwise noted)

**SUPPLY CURRENT
vs
SUPPLY VOLTAGE**

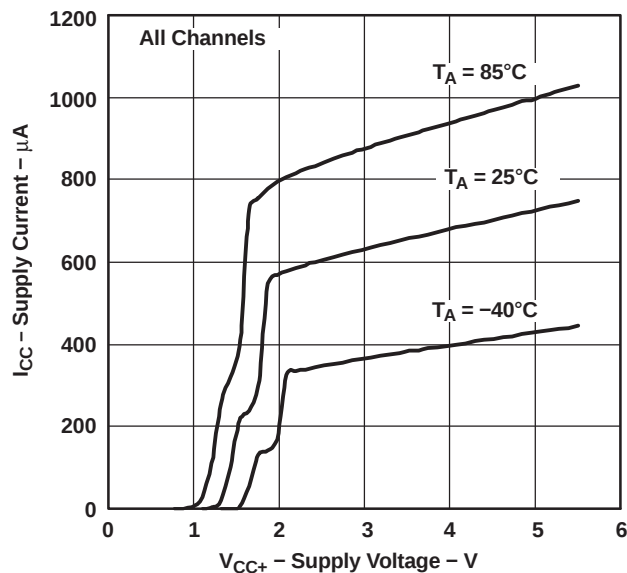


Figure 1.

**INPUT CURRENT
vs
TEMPERATURE**

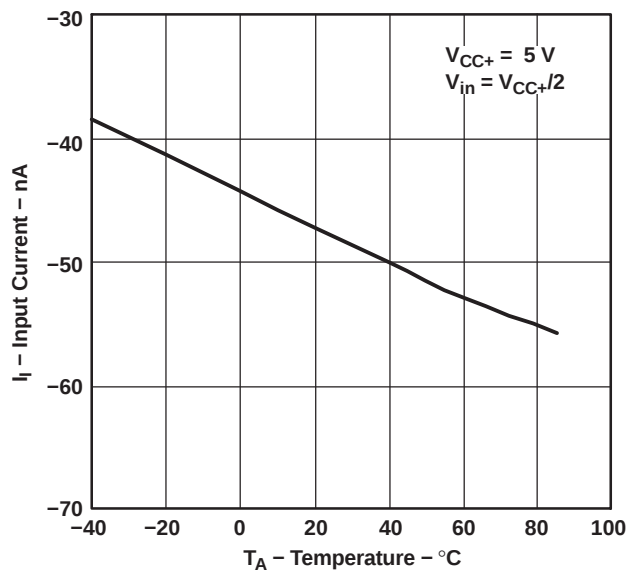


Figure 2.

**SOURCING CURRENT
vs
OUTPUT VOLTAGE**

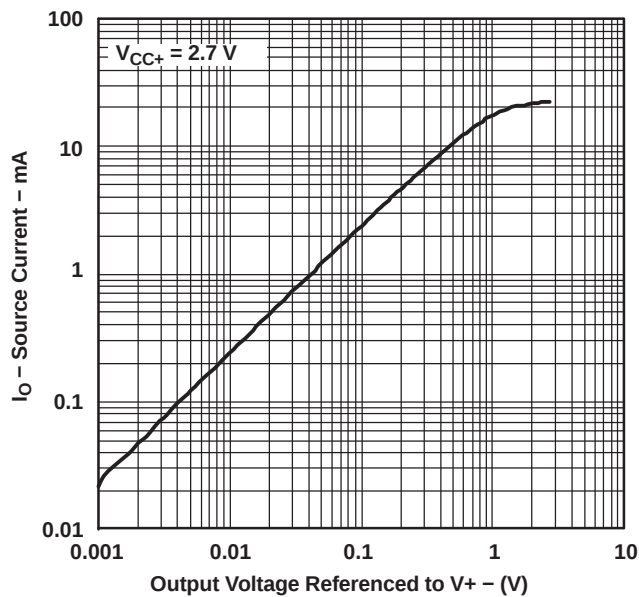


Figure 3.

**SOURCING CURRENT
vs
OUTPUT VOLTAGE**

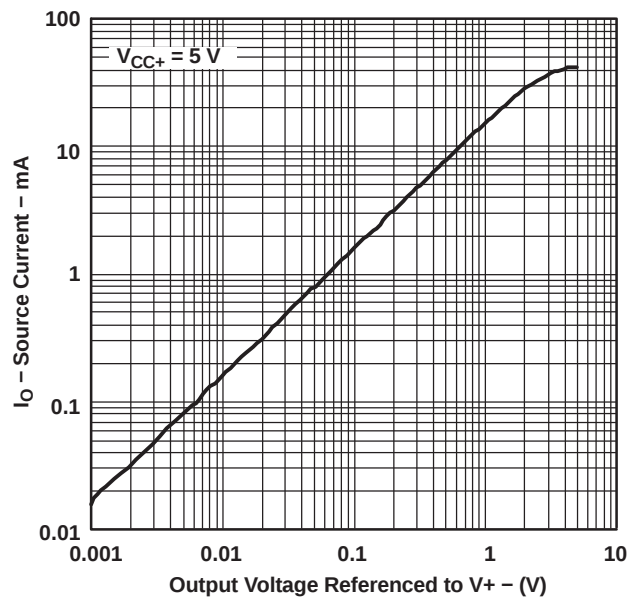
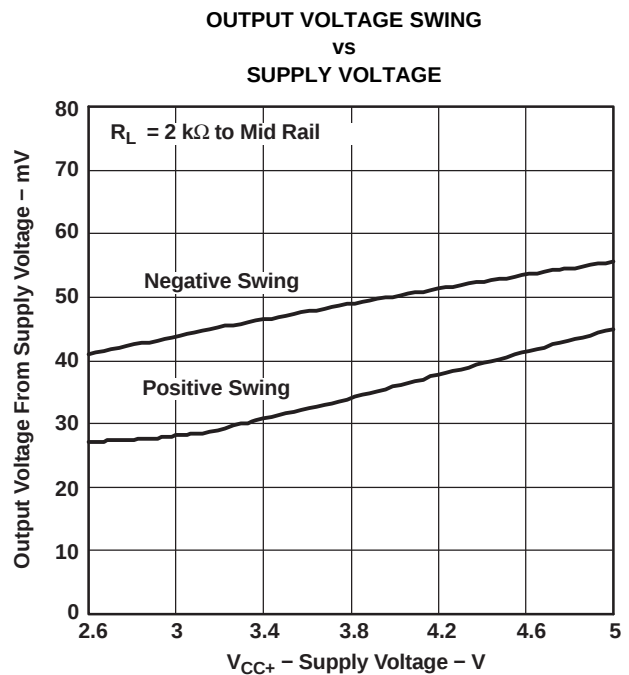
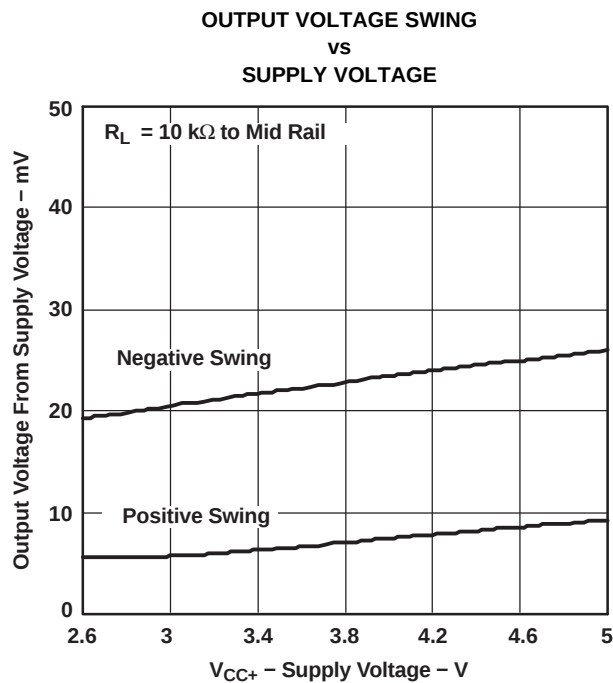
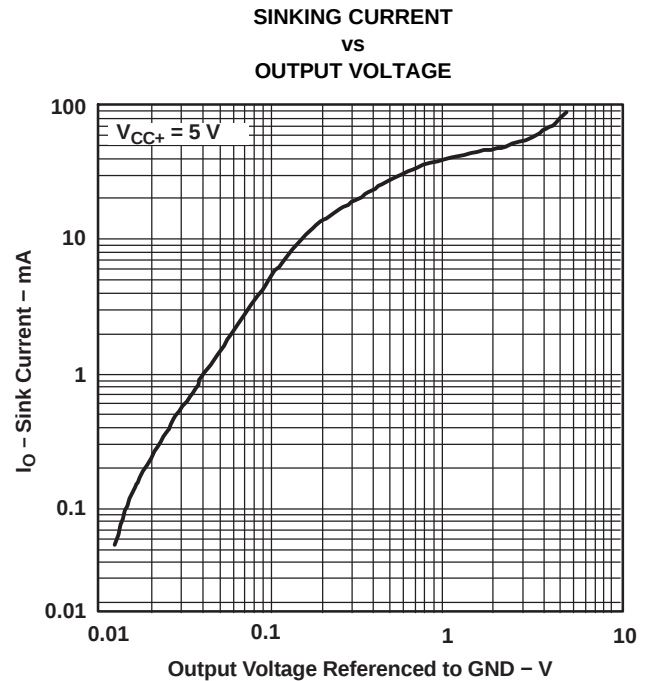
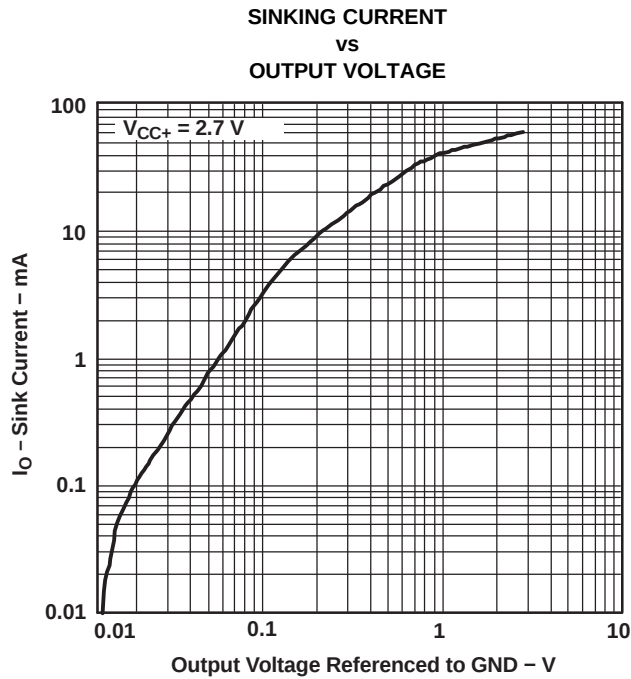


Figure 4.

TYPICAL CHARACTERISTICS (continued)

$T_A = 25^\circ\text{C}$, $V_{CC+} = 5\text{-V}$ single supply (unless otherwise noted)



TYPICAL CHARACTERISTICS (continued)

$T_A = 25^\circ\text{C}$, $V_{CC+} = 5\text{-V}$ single supply (unless otherwise noted)

OUTPUT VOLTAGE SWING

vs

SUPPLY VOLTAGE

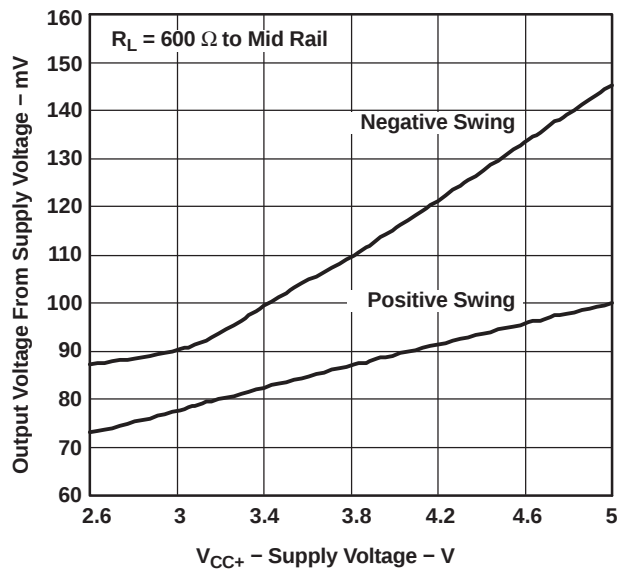


Figure 9.

OUTPUT VOLTAGE SWING

vs

LOAD RESISTANCE

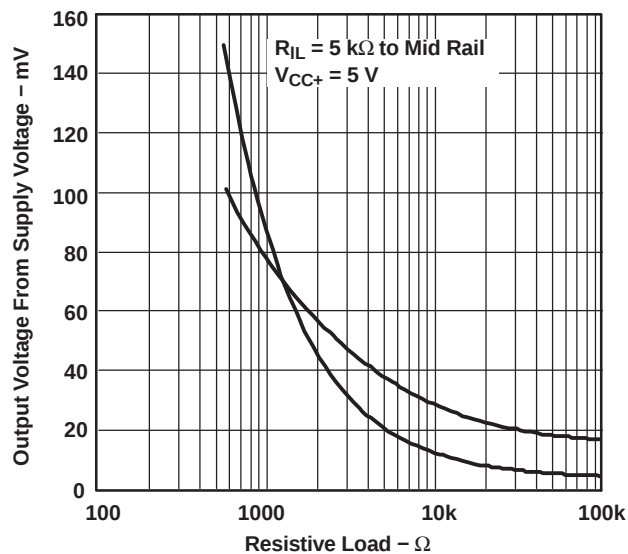


Figure 10.

CROSSTALK REJECTION

vs

FREQUENCY

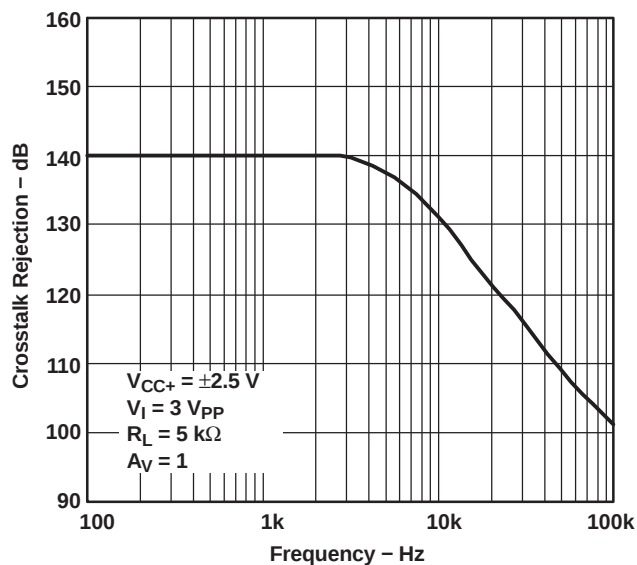


Figure 11.

+PSRR

vs

FREQUENCY

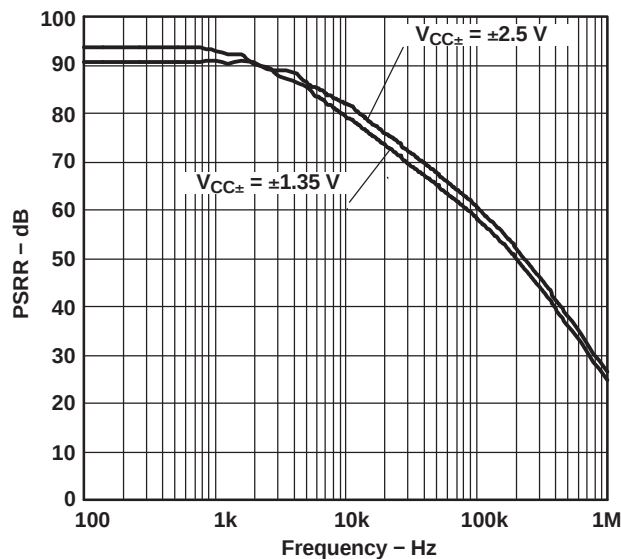
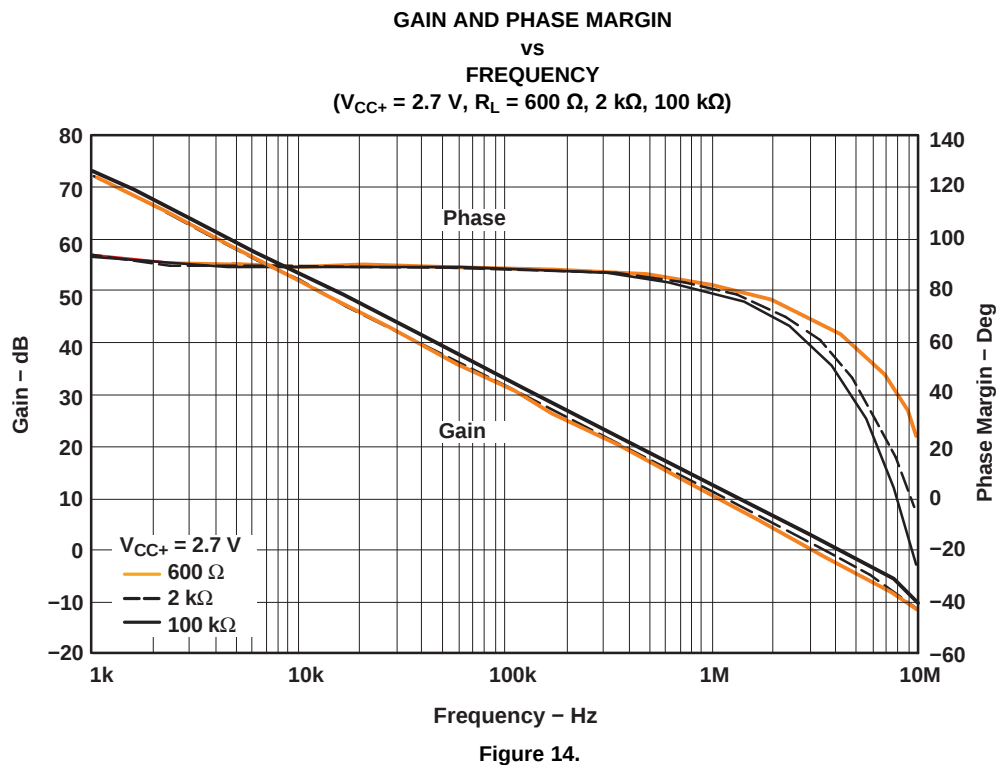
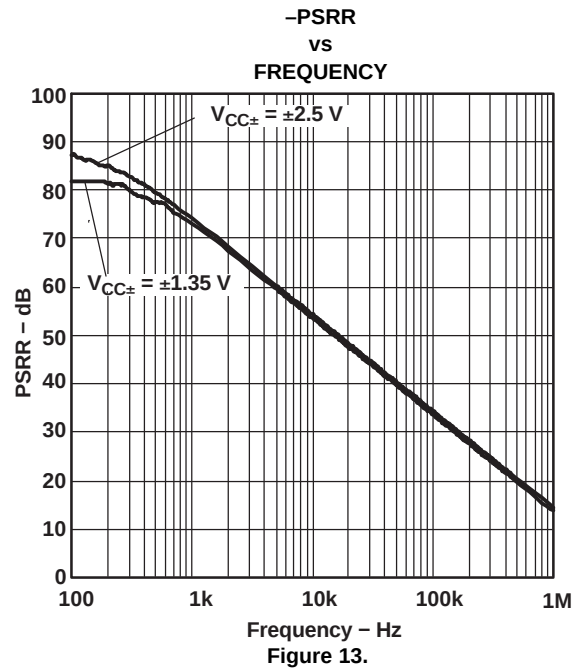


Figure 12.

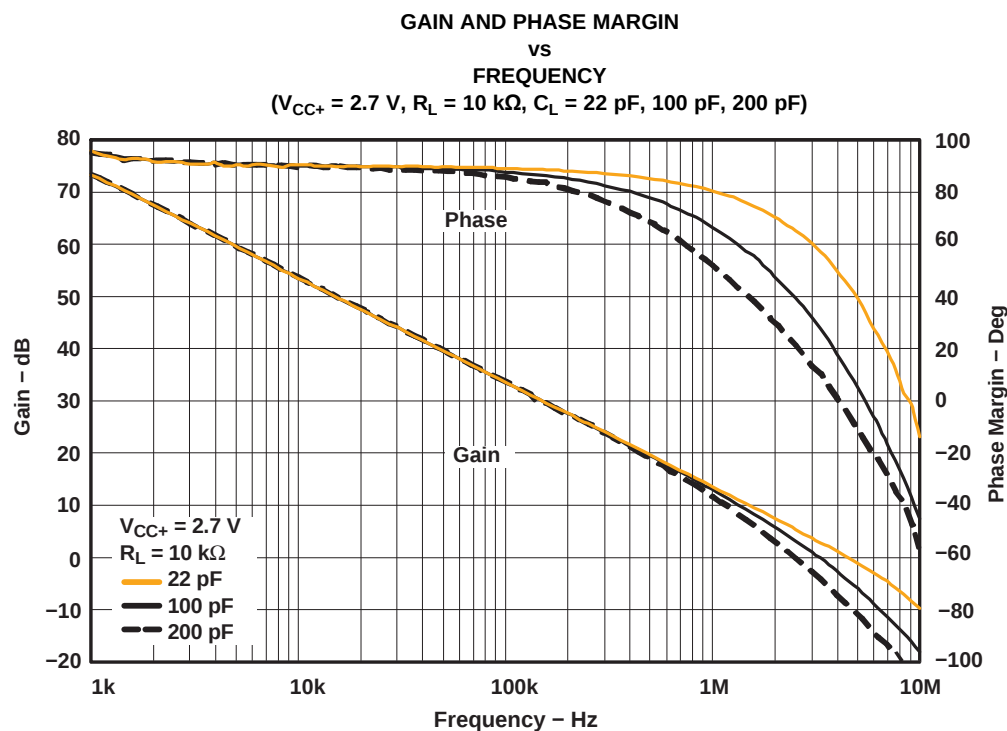
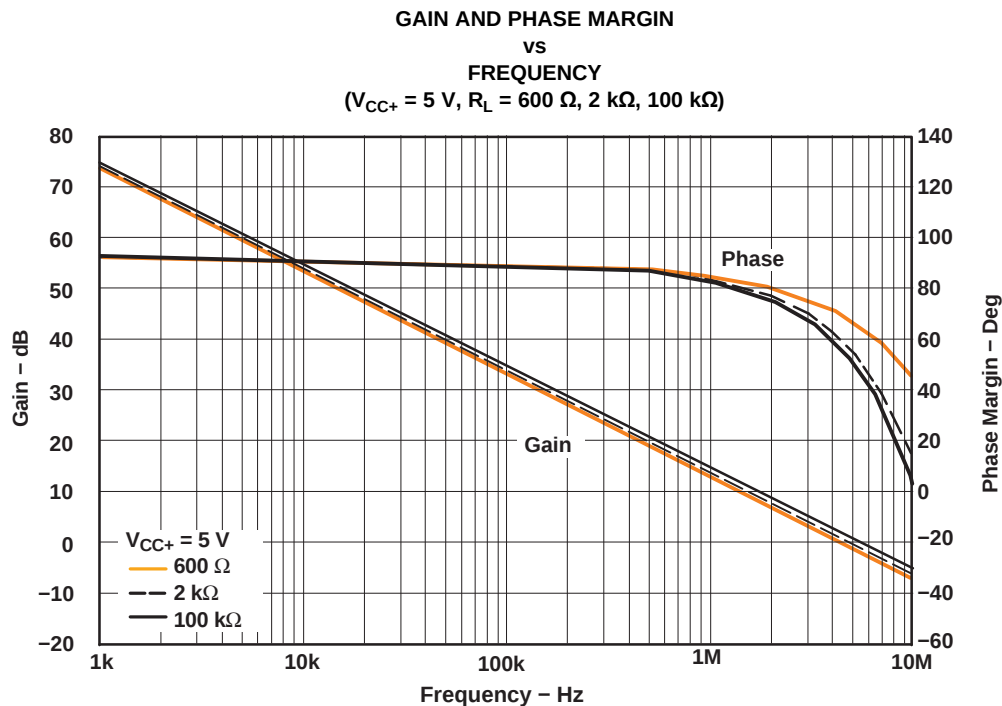
TYPICAL CHARACTERISTICS (continued)

$T_A = 25^\circ\text{C}$, $V_{CC+} = 5\text{-V}$ single supply (unless otherwise noted)



TYPICAL CHARACTERISTICS (continued)

$T_A = 25^\circ\text{C}$, $V_{CC+} = 5\text{-V}$ single supply (unless otherwise noted)



TYPICAL CHARACTERISTICS (continued)

$T_A = 25^\circ\text{C}$, $V_{CC+} = 5\text{-V}$ single supply (unless otherwise noted)

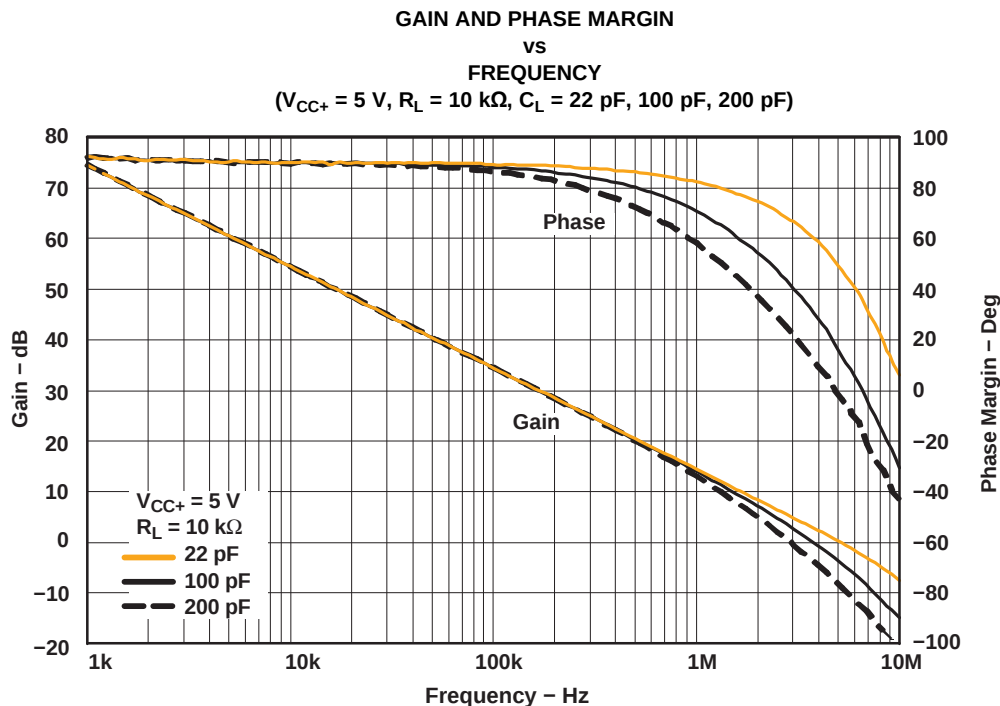


Figure 17.

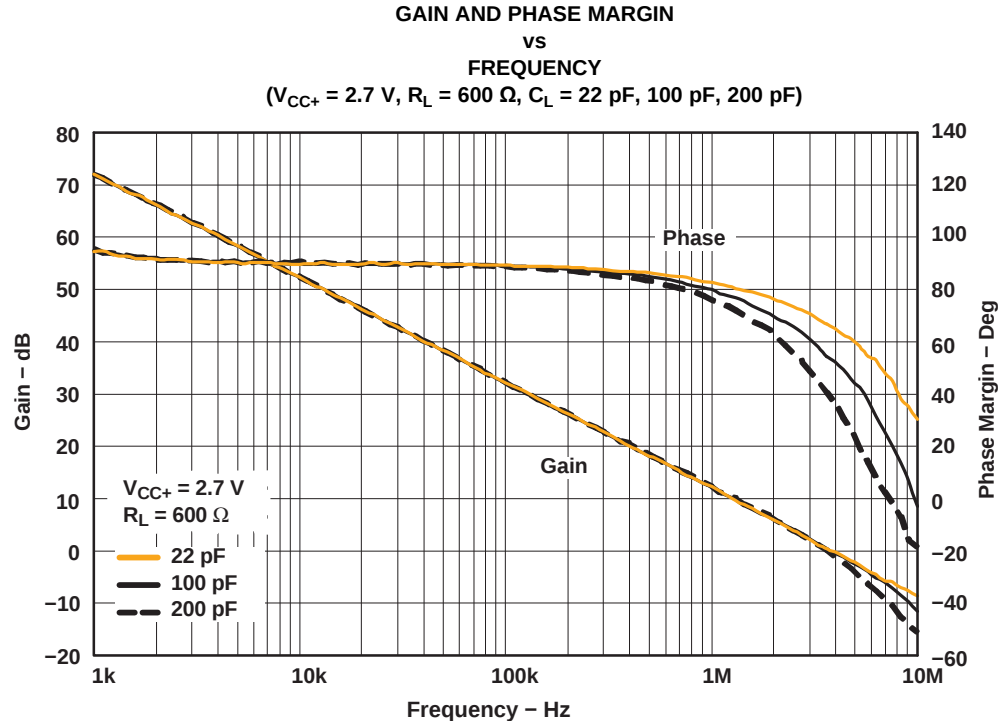


Figure 18.

TYPICAL CHARACTERISTICS (continued)

$T_A = 25^\circ\text{C}$, $V_{CC+} = 5\text{-V}$ single supply (unless otherwise noted)

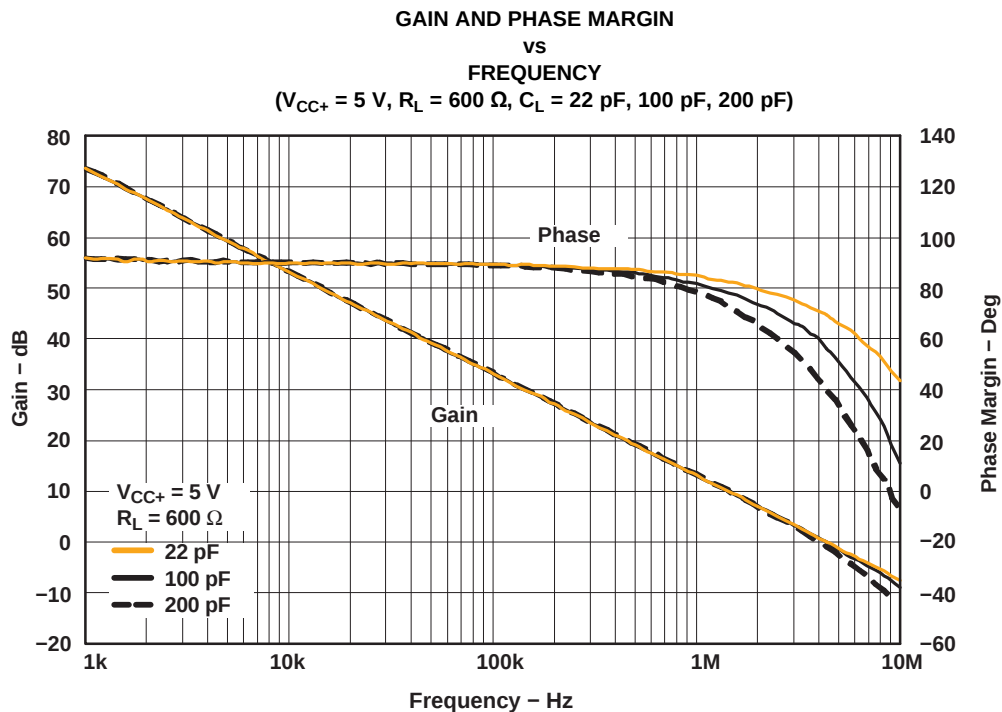


Figure 19.

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
LMV821QDBVRQ1	OBSOLETE	SOT-23	DBV	5		TBD	Call TI	Call TI	-40 to 125		

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check <http://www.ti.com/productcontent> for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead/Ball Finish - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

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OTHER QUALIFIED VERSIONS OF LMV821-Q1 :

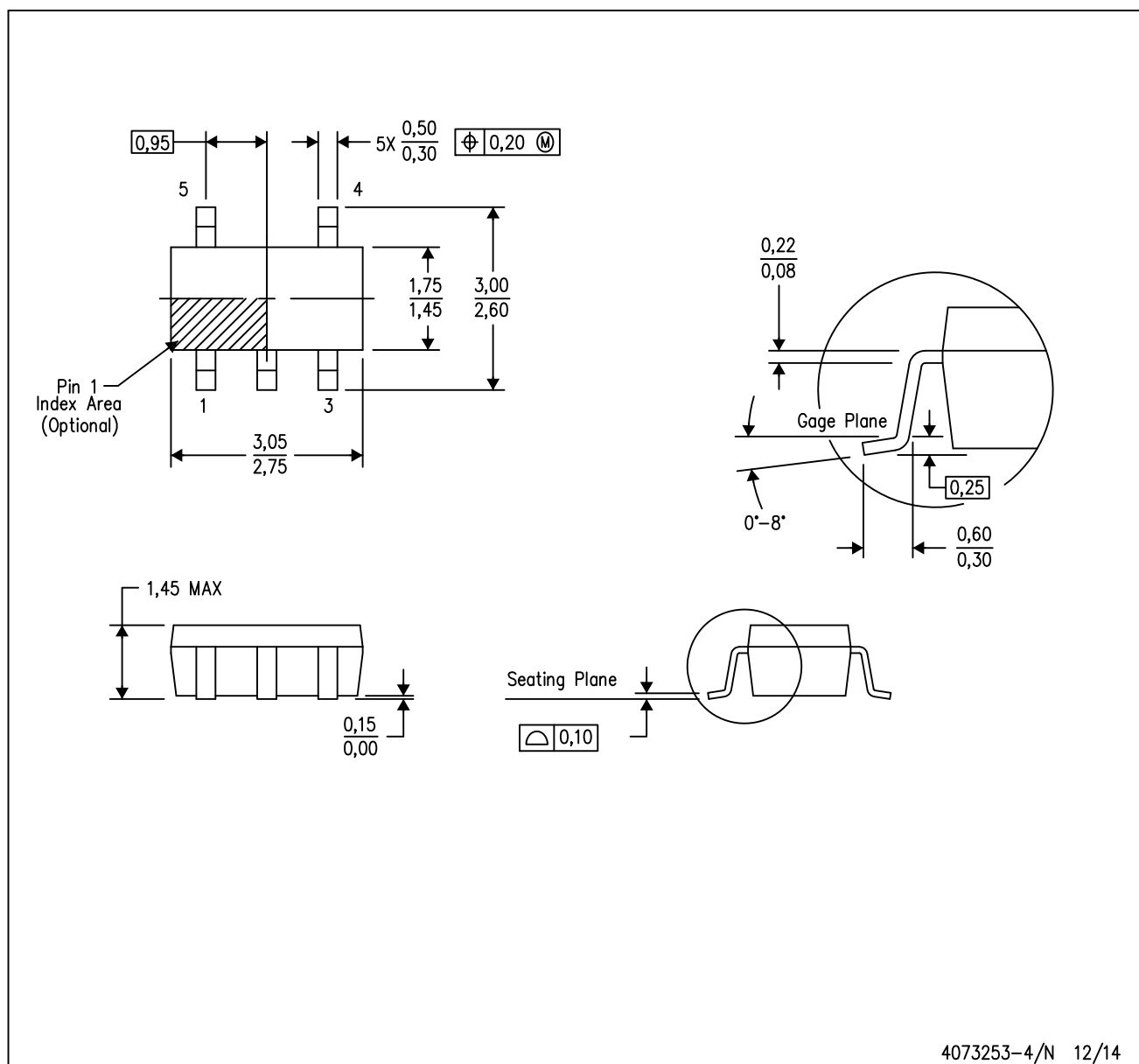
- Catalog: [LMV821](#)

NOTE: Qualified Version Definitions:

- Catalog - TI's standard catalog product

DBV (R-PDSO-G5)

PLASTIC SMALL-OUTLINE PACKAGE



- NOTES:
- All linear dimensions are in millimeters.
 - This drawing is subject to change without notice.
 - Body dimensions do not include mold flash or protrusion. Mold flash and protrusion shall not exceed 0.15 per side.
 - Falls within JEDEC MO-178 Variation AA.

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